

### DFT-based modeling of interface segregation in metals

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#### Thermodynamics

$$\boxed{\frac{c_k}{1 - c_k} = \frac{c_0}{1 - c_0} exp \frac{-E_{seg}^{gb}}{k_B T}}$$



**Kinetics** 

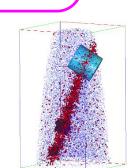


Structure

Goal:GB chemistry simulation

Goal: GB property simulation

Validation with experiment

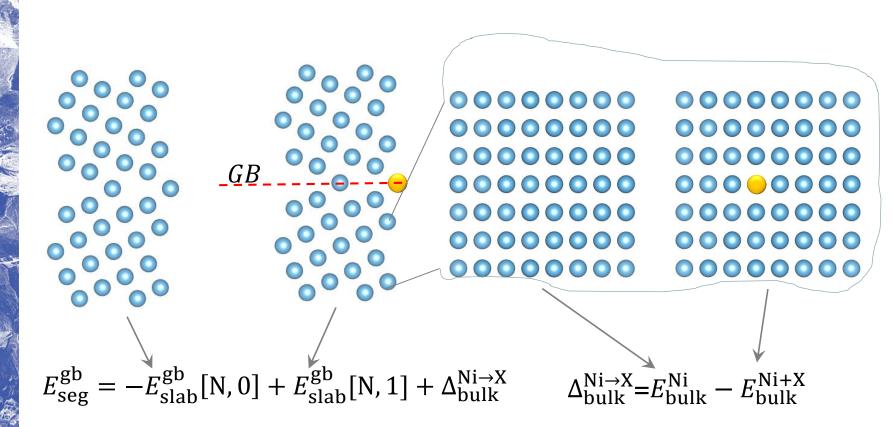


#### Introduction: impurity segregation from DFT



#### Impurity segregation to grain boundaries:

- Even tiny amounts of impurities segregating to interfaces can affect properties of Cu Characteristic fundamental quantity:
- Segregation energy  $E^{seg}$ : from density functional theory (DFT)

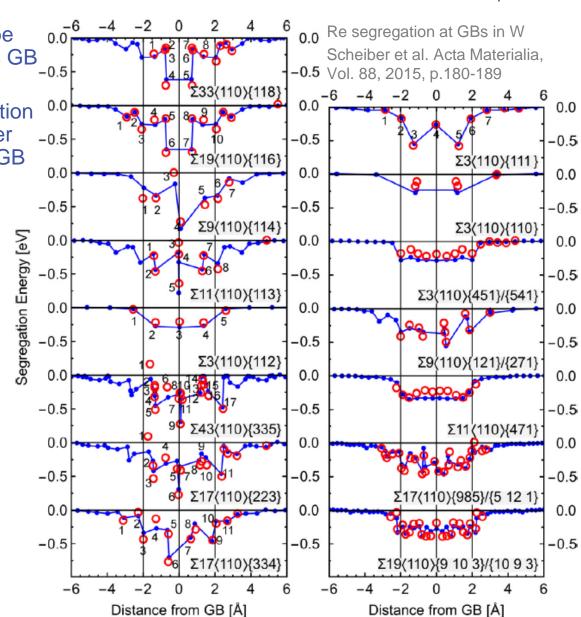


#### Introduction: impurity segregation from DFT at 0K



#### Segregation profiles:

- More than 1 GB site can be occupied (valid regardless GB type)
- Most efficient GB segregation sites are located at a rather narrow distance from the GB plane (GB width δ ≈ 5Å)



#### Introduction: impurity segregation from DFT at 0K

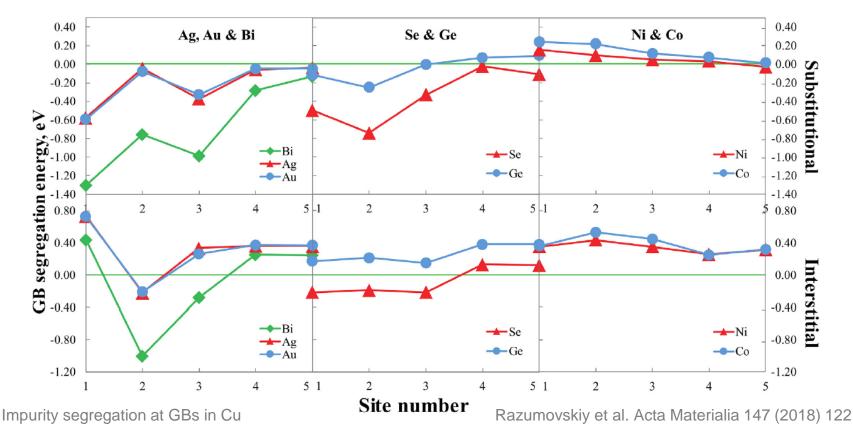


#### Segregation profiles:

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- More than 1 GB site can be occupied (valid regardless GB type)
- Most efficient GB segregation sites are located at a rather narrow distance from the GB plane (GB width  $\delta \approx 5 \text{Å}$ )

 This result is valid for all types of impurities (interstitial & substitutional)



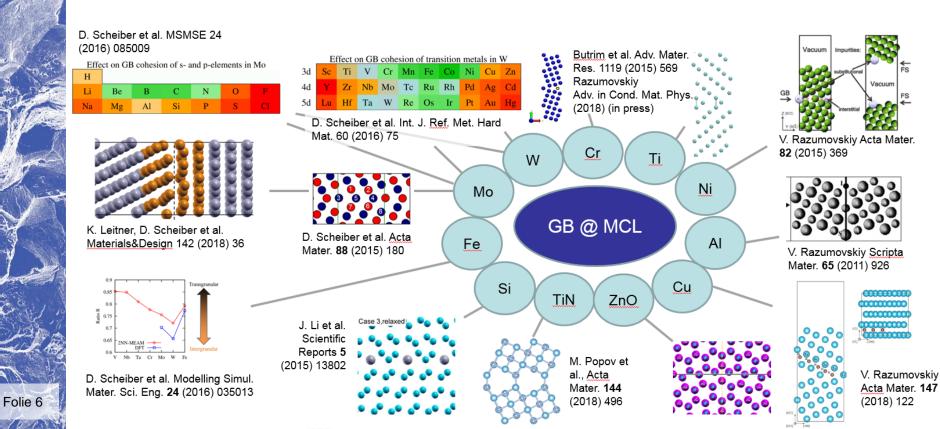
#### Introduction: impurity segregation from DFT at 0K



#### Segregation profiles:

- More than 1 GB site can be occupied (valid regardless GB type)
- Most efficient GB segregation sites are located at a rather narrow distance from the GB plane (GB width δ ≈ 5Å)

- This result is valid for all types of impurities (interstitial & substitutional)
- This result is valid for all studied (by us) materials





## How to process DFT segregation profiles:

- segregation isotherms (GB concentration
- & effective segregation energies)

#### **DFT+ McLean vs. Experiment: methodology**



#### Segregation at T>0

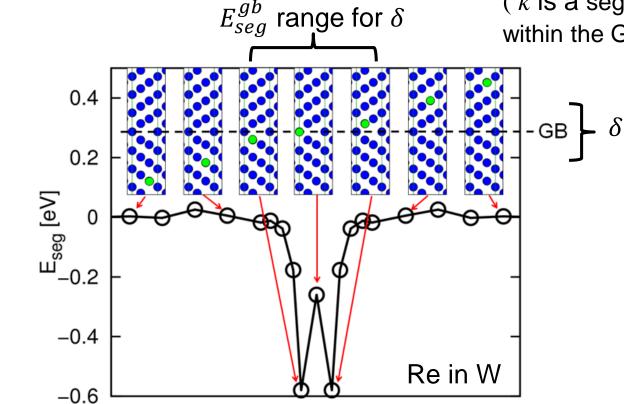
Langmuir-McLean segregation isotherm (Oriani's equation):

$$\frac{c_{gb}}{1 - c_{gb}} = \frac{c_{bulk}}{1 - c_{bulk}} exp \frac{-E_{seg}^{gb}}{k_B T}$$

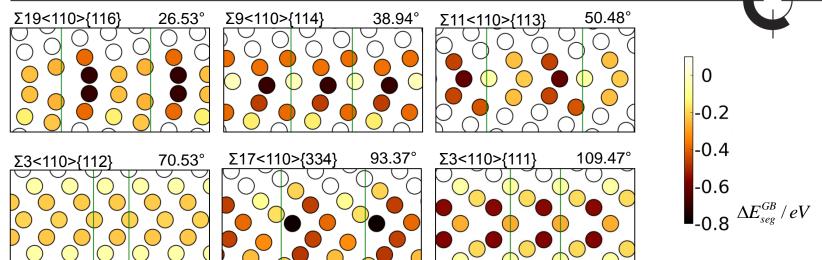
Average concentration within a GB width  $\delta$ :

$$c_{gb} = \langle c_k \rangle = \frac{1}{N(k)} \sum_{k \in \mathcal{S}} c_{gb}^k$$

( k is a segregation site within the GB width  $\delta$ )







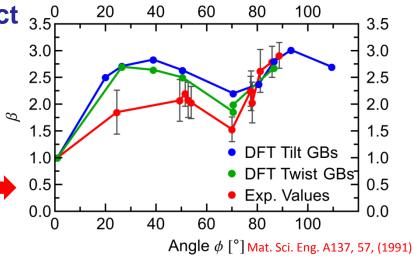
Re segregation at GBs in W)

DFT+ McLean vs. Experiment (direct comparison)

Enhancement factor β of Re as a function of misorientation angle φ at 1913 K in a WRe<sub>25</sub> alloy.

$$\frac{c_k}{1 - c_k} = \frac{c_0}{1 - c_0} \exp\left(-\frac{\Delta E_{seg}^{GB}}{kT}\right) \Rightarrow \beta = \frac{\sum_{k \in GB} c_k}{N_{GB} c_0}$$

- Good agreement with experiment!
- Prediction possible with simple McLean!



#### DFT+ McLean vs. Experiment: indirect comparison



#### Segregation at T>0

Langmuir-McLean segregation isotherm (Oriani's equation):

Average concentration within a GB width  $\delta$ :

Effective (thermally activated) impurity segregation energy in Cu for multiple interfacial sites k at any temperature T:

$$\frac{c_{gb}}{1 - c_{gb}} = \frac{c_{bulk}}{1 - c_{bulk}} exp \frac{-E_{seg}^{gb}}{k_B T}$$

$$c_{gb} = \langle c_k \rangle = \frac{1}{N(k)} \sum_{k \in S} c_{gb}^k$$

$$\tilde{E}_{seg}^{gb} = k_B T \left[ ln \left( \frac{c_{bulk}}{1 - c_{bulk}} \right) - ln \left( \frac{\langle c_{gb}^k \rangle}{1 - \langle c_{gb}^k \rangle} \right) \right]$$

Ag & Bi segregation to ∑5 GB in Cu:

[1] Razumovskiy et al. ActaMaterialia 147 (2018) 122;[2] Alber et al. Acta Mat. 47 (1999) 4047;

[3] Divinski et al Prys. (2012) 144104.	Rev B 85
(2012) 144104.	

Energy, kJ/mol	Ag	Bi
$E_{seg}^{gb}$ (min) @ 0K [1]	-55	-126
$\tilde{E}_{seg}^{gb}$ @ 800K [1]	-40	-84
Experiment [2-3]	-28 (+/15)	-89 (+/4)



## How to process DFT segregation profiles:

- segregation isotherms (GB concentration
   & effective segregation energies)
- impurity depletion in the bulk (GB size effect)

#### **Introducing grain size effects**



#### Ratio of GB/bulk sites:

Site density

$$f = \frac{N_{GB}}{N_{Bulk}} = \frac{\delta A_{GB} \chi}{V_{Bulk} \chi} = \frac{6\delta a^2}{2a^3} = \frac{3\delta}{a}$$

Half of the GB width (it is assumed that 2 grains share a GB)

Grain size

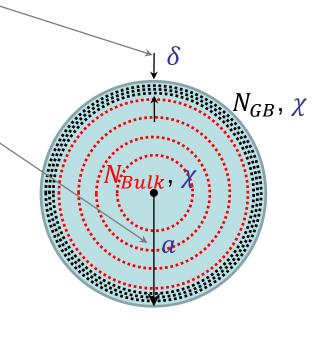
#### additional condition to McLean

$$\frac{c_k}{1 - c_k} = \frac{c_{bulk}}{1 - c_{bulk}} exp \frac{-E_{seg}^{gb}(k)}{k_B T}$$

occupancy of bulk sites occupancy of GB sites

$$c_{bulk}^0 = (1-f)c_{bulk} + f\sum_k \frac{c_k}{N_k} \text{ Number of GB segregation sites (from DFT)}$$

Nominal composition (bulk)







#### Segregation at T>0

McLean segregation isotherm (Oriani's equation):

#### Grain size dependence at T>0

Actual  $c_{bulk}$  depends on the ration of the GB to bulk sites  $f = \frac{N_{GB}}{N_{Bulk}}$  and on the nominal bulk concentration of the solute  $c_{bulk}^0$ :

$$\frac{c_{gb}}{1 - c_{gb}} = \frac{c_{bulk}}{1 - c_{bulk}} exp \frac{-E_{seg}^{gb}}{k_B T}$$

$$c_{bulk}^0 = (1 - f)c_{bulk} + f\sum_{k} c_{gb}^k$$

#### Methodology: GB impurity concentration at T>0

#### Segregation at T>0

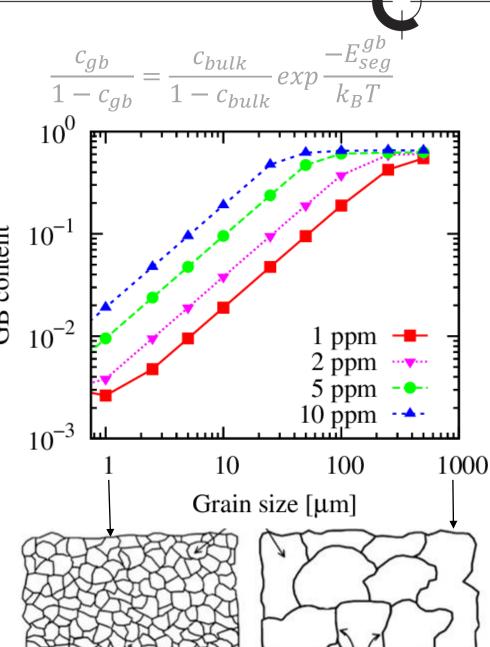
McLean segregation isotherm (Oriani's equation):

#### Grain size dependence at T>0

Actual  $c_{bulk}$  depends on the ration of the GB to bulk sites  $f=\frac{N_{GB}}{N_{Bulk}}$  and on the nominal bulk concentration of the solute  $c_{bulk}^0$ :

Sulfur in Ni @ 1000K

(Based on ∑5(210) GB segregation profile DFT calculations)





## How to process DFT segregation profiles:

- segregation isotherms (GB concentration
   & effective segregation energies)
- impurity deplition in the bulk (GB size effect)
- site competition at GB



#### One segregating element:

$$\frac{c_k}{1 - c_k} = \frac{c_0}{1 - c_0} exp \frac{-E_{seg}^{gb}(k)}{k_B T}$$

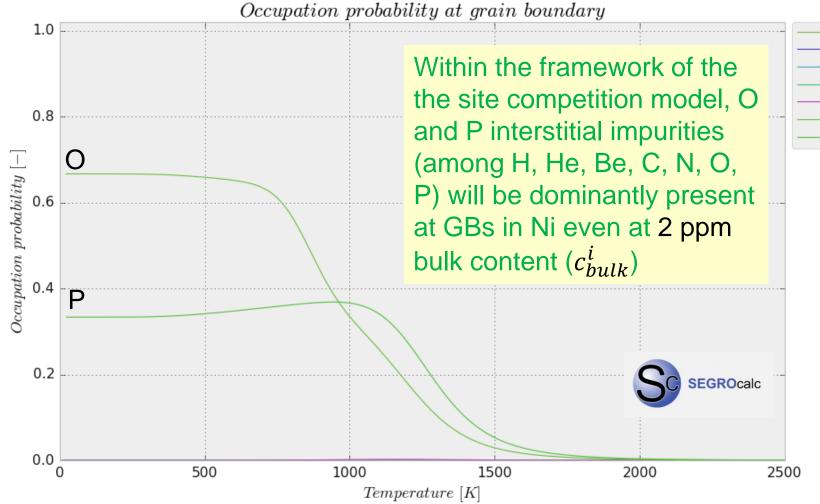
Multiple segregating elements:

$$\frac{c_k^i}{1 - \sum_i c_k^i} = \frac{c_0^i}{1 - \sum_i c_0^i} exp \frac{-E_{seg}^{i,gb}(k)}{k_B T}$$

 $c_k^i$  of a solute i depends on the GB concentration and bulk concentration of all other solutes

#### Interstitial element site competition with H





For a multicomponent system  $c_{gb}^{i}$  of solute i depends on the GB concentration and bulk concentration of all other solutes:

$$\frac{c_{gb}^{i}}{1 - \sum_{i} c_{gb}^{i}} = \frac{c_{bulk}^{i}}{1 - \sum_{i} c_{bulk}^{i}} exp \frac{-E_{seg}^{gb}}{k_{B}T}$$



## How to process DFT segregation profiles:

- segregation isotherms (GB concentration
   & effective segregation energies)
- impurity deplition in the bulk (GB size effect)
- site competition at GB
- combine with cohesive energy calculations for evaluation of the cohesive strength of alloys

#### Effect of solutes on cohesive strength





Partial cohesive energy

$$\chi_i = \frac{\partial E_{\text{coh}}}{\partial c_i}$$

$$Crystal$$

GB cohesion

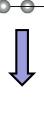
Work of separation change

$$au \; \eta = rac{W^0_{sep} - W^{imp}_{sep}}{\Gamma}$$

 $\eta < 0$ : strengthening

 $\eta > 0$ : embrittlement

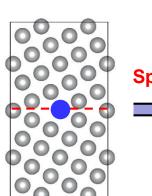
#### Free Surface (FS)



Free atoms



 $\chi < 0$ : destrengthening

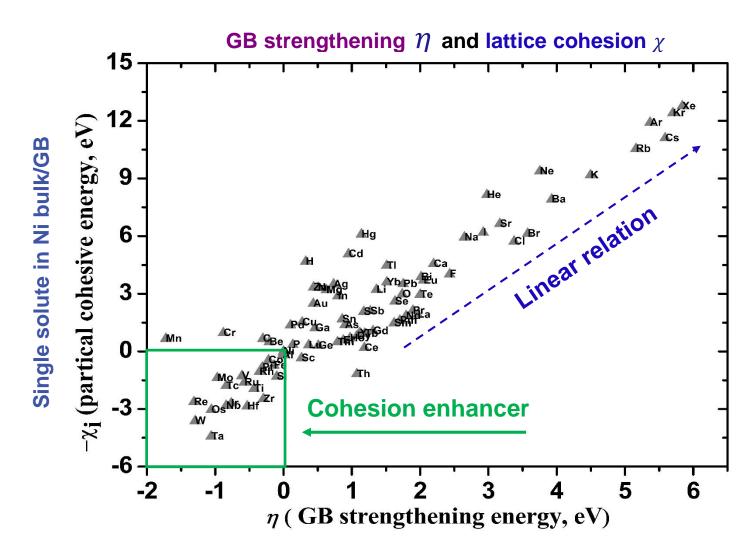


GB

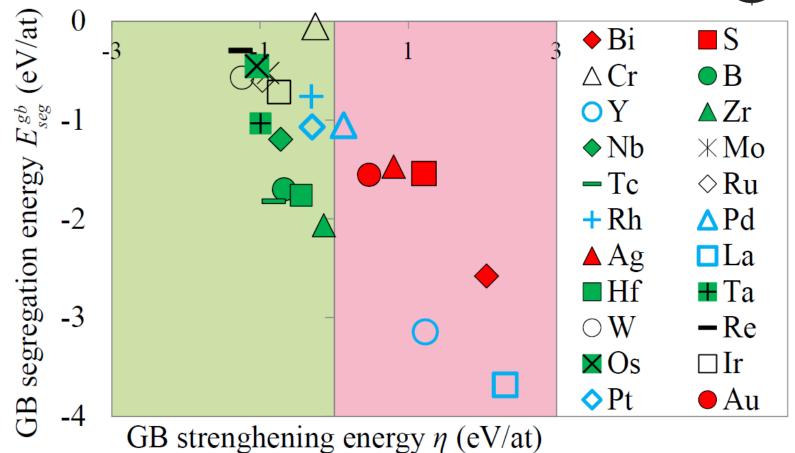


### Solute effect on the cohesion of Ni bulk and GB new (extended) data









**Fig. 3.**  $E_{seg}^{gb} - \eta$  map (GB segregation energy vs. GB strengthening energy). Elements that strengthen GB are located on the left side of the figure (green area of the plot); elements that embrittle the GB are located on the right side of the figure (red area of the plot). (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)

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#### **Summary: towards ICGBE**



#### Segregation at T>0

McLean segregation isotherm for a GB with multiple sites k

$$\frac{c_{gb}}{1 - c_{gb}} = \frac{c_{bulk}}{1 - c_{bulk}} exp \frac{-E_{seg}^{gb}}{k_B T};$$

$$\left| c_{gb} = \langle c_k \rangle = \frac{1}{N(k)} \sum_{k \in \delta} c_{gb}^k; \quad \tilde{E}_{seg}^{gb} = k_B T \left[ ln \left( \frac{c_{bulk}}{1 - c_{bulk}} \right) - ln \left( \frac{\langle c_{gb}^k \rangle}{1 - \langle c_{gb}^k \rangle} \right) \right] \right|$$

Grain size dependence at T>0

additional condition:

# Combine $c_{bulk} = (1-f)c_{bulk}^0 + \frac{f}{N_k}\sum_k c_k$

Site competition at T>0

 $c_{gb}^i$  of solute i dependence on the GB concentration  $c_{gb}^{j,j\neq i}$  and bulk concentration  $c_{bulk}^{j,j\neq i}$  of other solutes:

$$\frac{c_{gb}^{i}}{1 - \sum_{i} c_{gb}^{i}} = \frac{c_{bulk}^{i}}{1 - \sum_{i} c_{bulk}^{i}} exp \frac{-E_{seg}^{gb}}{k_{B}T}$$

GB and bulk cohesion

$$\eta = E_{seg}^{gb} - E_{seg}^{fs}; \chi_i = \frac{\partial E_{coh}}{\partial c_i}$$



### Thank you for your attention

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